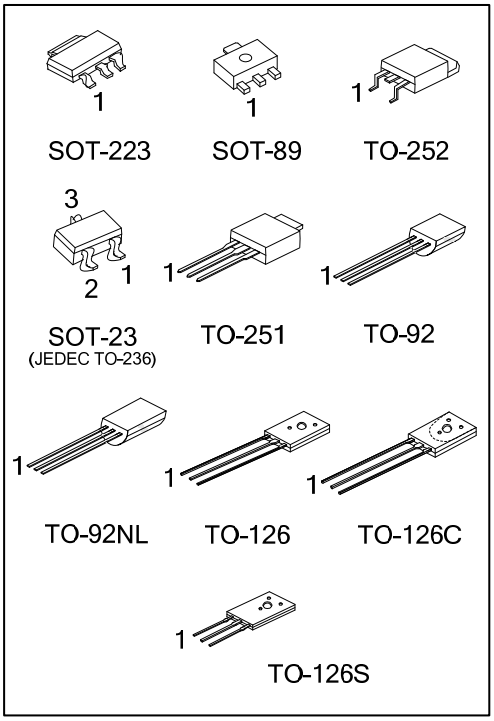
2SD669/A

NPN SILICON TRANSISTOR

BIPOLAR POWER GENERAL PURPOSE TRANSISTOR



■ APPLICATIONS

* Low frequency power amplifier complementary pair with UTC 2SB649/A

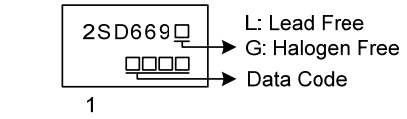
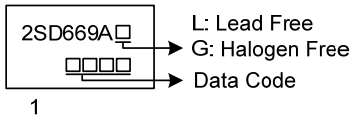
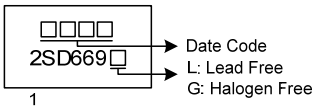
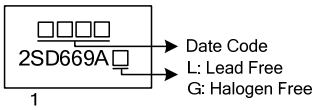
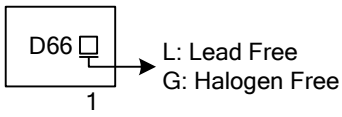
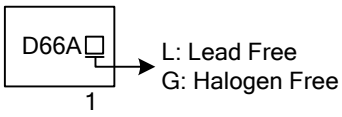
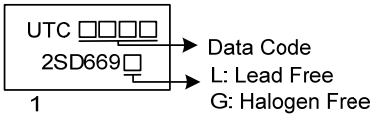
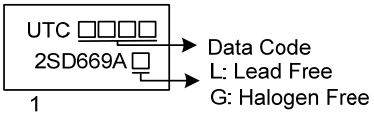
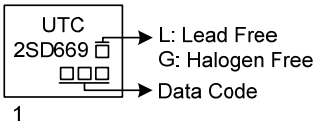
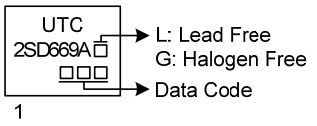
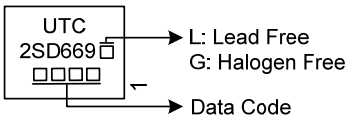
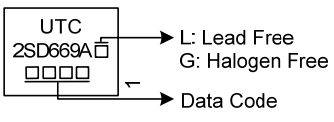
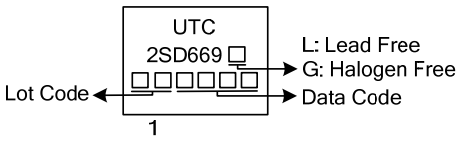
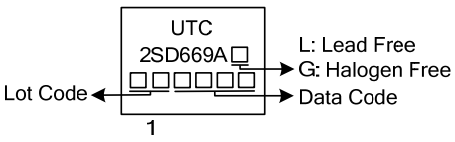
■ ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
2SD669xL-x-AA3-R	2SD669xG-x-AA3-R	SOT-223	B	C	E	Tape Reel
2SD669xL-x-AB3-R	2SD669xG-x-AB3-R	SOT-89	B	C	E	Tape Reel
2SD669xL-x-AE3-R	2SD669xG-x-AE3-R	SOT-23	B	E	C	Tape Reel
2SD669xL-x-AE3-6-R	2SD669xG-x-AE3-6-R	SOT-23	E	B	C	Tape Reel
2SD669xL-x-T60-K	2SD669xG-x-T60-K	TO-126	E	C	B	Bulk
2SD669xL-x-T6C-K	2SD669xG-x-T6C-K	TO-126C	E	C	B	Bulk
2SD669xL-x-T6S-K	2SD669xG-x-T6S-K	TO-126S	E	C	B	Bulk
2SD669xL-x-T92-B	2SD669xG-x-T92-B	TO-92	E	C	B	Tape Box
2SD669xL-x-T92-K	2SD669xG-x-T92-K	TO-92	E	C	B	Bulk
2SD669xL-x-T92-R	2SD669xG-x-T92-R	TO-92	E	C	B	Tape Reel
2SD669xL-x-T9N-B	2SD669xG-x-T9N-B	TO-92NL	E	C	B	Tape Box
2SD669xL-x-T9N-K	2SD669xG-x-T9N-K	TO-92NL	E	C	B	Bulk
2SD669xL-x-T9N-R	2SD669xG-x-T9N-R	TO-92NL	E	C	B	Tape Reel
2SD669xL-x-TM3-T	2SD669xG-x-TM3-T	TO-251	B	C	E	Tube
2SD669xL-x-TN3-T	2SD669xG-x-TN3-T	TO-252	B	C	E	Tube
2SD669xL-x-TN3-R	2SD669xG-x-TN3-R	TO-252	B	C	E	Tape Reel

2SD669xL-x-AE3-6-R
- (1)Packing Type
- (2)Pin Assignment
- (3)Package Type
- (4)Rank
- (5)Lead Plating
- (6) Collector-Emitter Voltage

(1) B: Tape Box, K: Bulk, R: Tape Reel, T: Tube
(2) refer to Pin Assignment
(3) AA3: SOT-223, AB3: SOT-89, AE3: SOT-23
T60: TO-126, T6C: TO-126C, T6S: TO-126S
TM3: TO-251, TN3: TO-252, T92: TO-92
T9N: TO-92NL
(4) x: refer to Classification of h_{FE1}
(5) L: Lead Free, G: Halogen Free
(6) A: 160V, Blank: 120V

■ MARKING INFORMATION

PACKAGE	MARKING	
	2SD669	2SD669A
SOT-223		
SOT-89		
SOT-23		
TO-126 TO-126C TO-126S		
TO-92		
TO-92NL		
TO-251 TO-252		

■ ABSOLUTE MAXIMUM RATING (T_A=25°C unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT
Collector-Base Voltage		V_{CBO}	180	V
Collector-Emitter Voltage	2SD669	V_{CEO}	120	V
	2SD669A		160	
Emitter-Base Voltage		V_{EBO}	5	V
Collector Current		I_C	1.5	A
Collector Peak Current		$I_{C(PEAK)}$	3	A
Power Dissipation	SOT-223/ SOT-89	P_D	0.5	W
	SOT-23		0.35	W
	TO-126/TO-126S		1.3	W
	TO-126C/TO-251		1	W
	TO-92/TO-92NL		0.6	W
	TO-252		2	W
Junction Temperature		T_J	150	°C
Storage Temperature		T_{STG}	-40 ~ +150	°C

Notes: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

■ HERMAL DATA

PARAMETER		SYMBOL	RATINGS	UNIT
Junction to Case	SOT-89	θ_{JC}	38	°C/W
	SOT-223		14	
	SOT-23		110	
	TO-92/TO-92NL		80	
	TO-126/TO-126S		6.25	
	TO-126C		10	
	TO-251/ TO-252		4.5	

■ ELECTRICAL CHARACTERISTICS (T_A=25°C, unless otherwise specified)

PARAMETER		SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector to Base Breakdown Voltage		BV_{CBO}	I_C=1mA, I_E=0	180			V
Collector to Emitter Breakdown Voltage	2SD669	BV_{CEO}	I_C=10mA, R_{BE}=∞	120			V
	2SD669A			160			
Emitter to Base Breakdown Voltage		BV_{EBO}	I_E=1mA, I_C=0	5			V
Collector Cut-off Current		I_{CBO}	V_{CB}=160V, I_E=0			10	μA
DC Current Gain		h_{FE1}	V_{CE}=5V, I_C=150mA (Note)	60		320	
		h_{FE2}	V_{CE}=5V, I_C=500mA (Note)	30			
Collector-Emitter Saturation Voltage		$V_{CE(SAT)}$	I_C=600mA, I_B=50mA (Note)			1	V
Base-Emitter Voltage		V_{BE}	V_{CE}=5V, I_C=150mA (Note)			1.5	V
Current Gain Bandwidth Product		f_T	V_{CE}=5V, I_C=150mA (Note)		140		MHz
Output Capacitance		C_{ob}	V_{CB}=10V, I_E=0, f=1MHz		14		pF

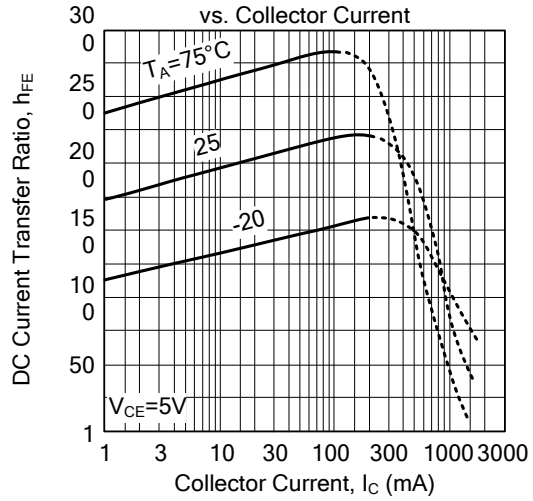
Note: Pulse test.

■ CLASSIFICATION OF h_{FE1}

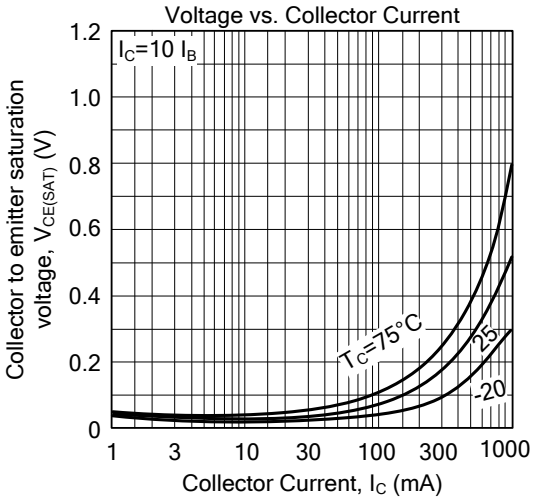
RANK	B	C	D
RANGE	60-120	100-200	160-320

■ TYPICAL CHARACTERISTICS

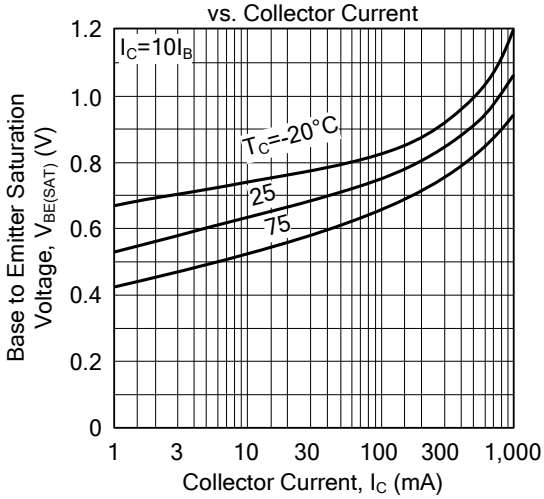
DC Current Transfer Ratio vs. Collector Current



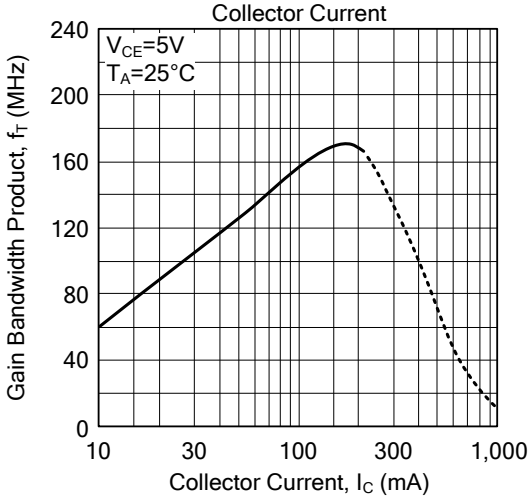
Collector to Emitter Saturation Voltage vs. Collector Current



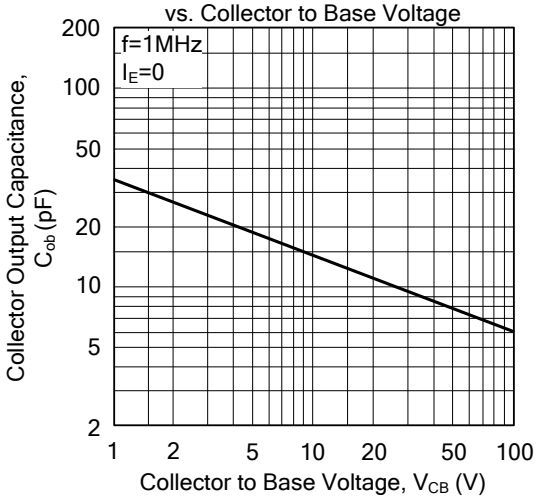
Base to Emitter Saturation Voltage vs. Collector Current



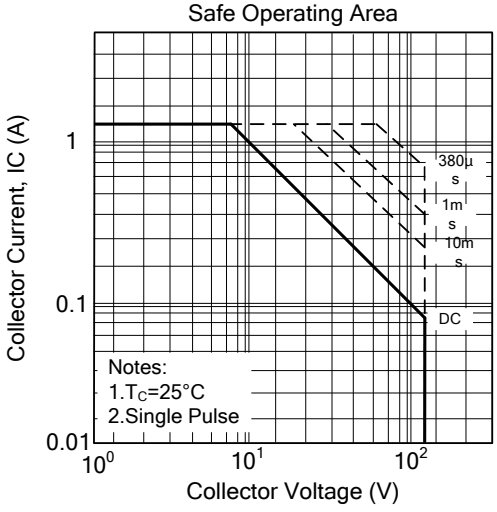
Gain Bandwidth Product vs. Collector Current



Collector Output Capacitance vs. Collector to Base Voltage



Safe Operating Area



■ TYPICAL CHARACTERISTICS(Cont.)